

## Monolithic Amplifier

**GVA-60+** 

 $50\Omega$  0.01 to 5 GHz

#### THE BIG DEAL

- Excellent Gain Flatness and Return Loss over 50-1000 MHz
- · High IP3 vs. DC Power consumption
- Broadband High Dynamic Range without external Matching Components
- Gain, 20 dB typ. at 0.4 GHz
- Gain flatness: ±0.3 dB over 50-1000 MHz
- Excellent Input Return Loss, up to 2 GHz, 17-24 dB
- High Pout, P1dB 20.0 dBm typ. at 0.4 GHz
- Excellent ESD protection, Class 1C for HBM
- No external matching components required



Generic photo used for illustration purposes only

CASE STYLE: DF782

#### +RoHS Compliant

The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

### **APPLICATIONS**

- Base station infrastructure
- Portable Wireless
- CATV & DBS
- MMDS & Wireless LAN
- LTE

### **PRODUCT OVERVIEW**

GVA-60+ (RoHS compliant) is an wideband amplifier fabricated using HBT technology and offers ultra flat gain over a broad frequency range and with high IP3. In addition, the GVA-60+, has good input and output return loss over a broad frequency range without the need for external matching components and has demonstrated excellent reliability. It has repeatable performance from lot to lot and is enclosed in a SOT-89 package for very good thermal performance.

### **KEY FEATURES**

Feature	Advantages		
Broad Band: 0.01 to 5.0 GHz	Broadband covering a broad range of IF frequencies and the primary wireless communications bands: Cellular, PCS, LTE, WiMAX		
High IP3 vs. DC power Consumption 40 dBm typical at 0.05 GHz 35 dBm typical at 0.85 GHz	The GVA-60+ matches industry leading IP3 performance relative to device size and power consumption. The combination of the design and HBT Structure provides enhanced linearity over a broad frequency range as evidence in the IP3 being typically 16 dB above the P 1dB point to 0.85 GHz. This feature makes this amplifier ideal for use in:  • Driver amplifiers for complex waveform up converter paths • Drivers in linearized transmit systems		
Outstanding Input Return Loss up to 1 GHz: better than 20 dB.	The GVA-60+ provides excellent input return loss: 20 dB up to 1 GHz and 16.8 dB up to 2 GHz making this amplifier an ideal IF gain block that can be embedded in RF chains that have highly reflective components, and still maintain good system performance		
No External Matching Components Required 10-24 dB to 2 GHz	GVA-60+ provides good Input and Output Return Loss without the need for any external matching components		

REV. B ECO-010563 GVA-60+ TH/RS/CP





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## ELECTRICAL SPECIFICATIONS<sup>1</sup> AT 25°C AND VCC=5V, UNLESS NOTED

Parameter	Condition (GHz)	Min.	Тур.	Max.	Units
Frequency Range		0.01		5	GHz
	0.05	18.3	20.3	22.4	
	0.4	_	20.1	_	
	0.85	_	19.8	_	
Gain	2.0	16.6	18.4	20.3	dB
	3.0	_	17.0	_	
	4.0	_	15.4	_	
	5.0	_	14.2	_	
	0.05	_	23.1	_	
	0.4	_	24.0	_	
	0.85	16.0	21.2	_	
Input Return Loss	2.0	_	16.8	_	dB
	3.0	_	11.5	_	
	4.0	_	8.9	_	
	5.0	_	8.1	_	
	0.05	_	11.2	_	
	0.4	_	11.8	_	
	0.85	10.0	12.0	_	
Output Return Loss	2.0	_	9.6	_	dB
•	3.0	_	8.0	_	
	4.0	_	7.5	_	
	5.0	_	7.8	_	
Reverse Isolation	2.0		25.2		dB
	0.05	0.05	20.1	_	
	0.4	0.4	19.9	_	
	0.85	0.85	19.5	_	
Output Power at 1dB Compression	2.0	_	17.9	_	dBm
, , , , , , , , , , , , , , , , , , ,	3.0	_	14.6	_	
	4.0	_	12.1	_	
	5.0	_	10.0	_	
	0.05		40.5		
	0.4		39.3		
	0.85		35.6		
Output IP3	2.0		28.9		dBm
•	3.0		24.5		
	4.0		21.5		
	5.0		19.3		
	0.05	_	3.9	5.9	
	0.4	_	4.0	6.0	
	0.85	_	4.0	_	
Noise Figure	2.0	_	4.1	_	dB
<b>3</b>	3.0	_	4.1	_	
	4.0	_	4.3	_	
	5.0	_	4.5	_	
Device Operating Voltage		4.8	5.0	5.2	V
Device Operating Current			92.0	99.0	mA
Device Current Variation vs. Temperature <sup>3</sup>			172		μΑ/°C
Device Current Variation vs. Voltage			0.041		mA/mW
Thermal Resistance, junction-to-ground lead			37		°C/W

<sup>(1)</sup> Measured on Mini-Circuits Characterization test board TB-313. See Characterization Test Circuit (Fig. 1)

<sup>(2)</sup> Low Frequency cut-off determined by external coupling capacitors and external bias choke. (3) Current at 85°C — Current at -45°C)/130

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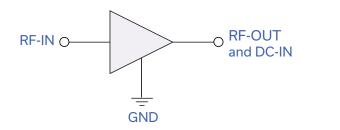
## **MAXIMUM RATINGS**

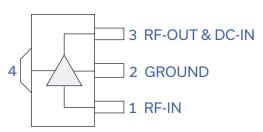
Parameter	Ratings			
Operating Temperature (ground lead)	-40°C to 85°C			
Storage Temperature	-65°C to 150°C			
Operating Current at 5V	140 mA			
Power Dissipation	0.7 W			
Input Power (CW)	28 dBm (10-1000 MHz, +5 minutes) 13 dBm (1000-5000 MHz, +5 minutes) 8 dBm (continuous) 28 dBm (10-1000 MHz, +5 minutes)			
DC Voltage on Pin 3	6V			

Permanent damage may occur if any of these limits are exceeded.
Electrical maximum ratings are not intended for continuous normal operation.

For continuous operation, do not exceed 5.2V device voltage.

## SIMPLIFIED SCHEMATIC AND PIN DESCRIPTION





Function	Pin Number	Description
RF IN	1	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
RF-OUT and DC-IN	3	RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit", Fig. 2
GND	2,4	Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance.

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## **CHARACTERIZATION TEST CIRCUIT**

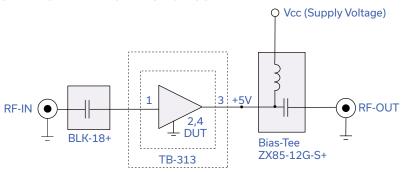


Fig 1. Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization test board TB-313) Gain, Return loss, Output power at 1dB compression (P1 dB), output IP3 (OIP3) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer.

#### Conditions:

- 1. Gain and Return loss: Pin= -25dBm
- 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, -18 dBm/ tone at input.

### RECOMMENDED APPLICATION CIRCUIT

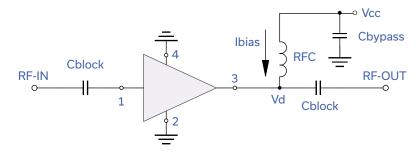


Fig 2. Test Board includes case, connectors, and components soldered to  $\ensuremath{\mathsf{PCB}}$ 

## **PRODUCT MARKING**



Marking may contain other features or characters for internal lot control